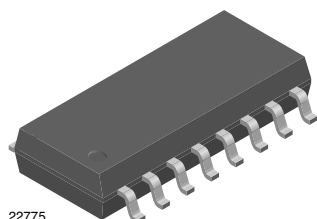
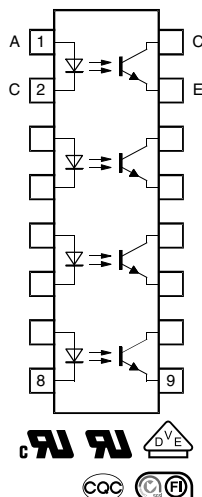


# Optocoupler, Phototransistor Output, Quad Channel, Half Pitch Mini-Flat Package



22775



## DESCRIPTION

The TCMT4100 series consist of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 16 pin (quad channel) package.

## FEATURES

- Low profile package (half pitch)
- AC isolation test voltage 3750 V<sub>RMS</sub>
- Low coupling capacitance of typical 0.3 pF
- Current transfer ratio (CTR) selected into groups
- Low temperature coefficient of CTR
- Wide ambient temperature range
- Material categorization:  
for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



## APPLICATIONS

- Programmable logic controllers
- Modems
- Answering machines
- General applications

## AGENCY APPROVALS

Safety application model number covering all products in this datasheet is TCMT4100. This model number should be used when consulting safety agency documents.

- UL1577, file no. E76222, double protection
- cUL, accordance to CSA component acceptance service no. 5A, double protection
- DIN EN 60747-5-5 (VDE 0884-5)
- FIMKO EN 60950-1
- CQC GB4943.1-2011 and GB8898-2011 (suitable for installation altitude below 2000 m)

## ORDERING INFORMATION

|             |   |   |   |   |   |   |   |
|-------------|---|---|---|---|---|---|---|
| T           | C | M | T | 4 | 1 | 0 | # |
| PART NUMBER |   |   |   |   |   |   |   |



| AGENCY CERTIFIED/PACKAGE      | CTR (%)                   |            |
|-------------------------------|---------------------------|------------|
|                               | 5 mA                      |            |
| UL, cUL, FIMKO, BSI, VDE, CQC | 50 to 600                 | 100 to 300 |
| SSOP-16, quad channel         | TCMT4100                  | TCMT4106   |
| SSOP-16, quad channel         | TCMT4100T0 <sup>(1)</sup> | -          |

## Notes

- Available only on tape and reel.
- <sup>(1)</sup> Product is rotated 180° in tape and reel cavity.



| <b>ABSOLUTE MAXIMUM RATINGS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified) |                                                |            |             |                    |
|--------------------------------------------------------------------------------------------------------|------------------------------------------------|------------|-------------|--------------------|
| PARAMETER                                                                                              | TEST CONDITION                                 | SYMBOL     | VALUE       | UNIT               |
| <b>INPUT</b>                                                                                           |                                                |            |             |                    |
| Reverse voltage                                                                                        |                                                | $V_R$      | 6           | V                  |
| Forward current                                                                                        |                                                | $I_F$      | 60          | mA                 |
| Forward surge current                                                                                  | $t_p \leq 10\text{ }\mu\text{s}$               | $I_{FSM}$  | 1.5         | A                  |
| Power dissipation                                                                                      |                                                | $P_{diss}$ | 100         | mW                 |
| Junction temperature                                                                                   |                                                | $T_j$      | 125         | $^{\circ}\text{C}$ |
| <b>OUTPUT</b>                                                                                          |                                                |            |             |                    |
| Collector emitter voltage                                                                              |                                                | $V_{CEO}$  | 70          | V                  |
| Emitter collector voltage                                                                              |                                                | $V_{ECO}$  | 7           | V                  |
| Collector current                                                                                      |                                                | $I_C$      | 50          | mA                 |
| Collector peak current                                                                                 | $t_p/T = 0.5$ , $t_p \leq 10\text{ ms}$        | $I_{CM}$   | 100         | mA                 |
| Power dissipation                                                                                      |                                                | $P_{diss}$ | 150         | mW                 |
| Junction temperature                                                                                   |                                                | $T_j$      | 125         | $^{\circ}\text{C}$ |
| <b>COUPLER</b>                                                                                         |                                                |            |             |                    |
| AC isolation test voltage (RMS)                                                                        | Related to standard climate 23/50<br>DIN 50014 | $V_{ISO}$  | 3750        | $V_{RMS}$          |
| Total power dissipation per channel                                                                    |                                                | $P_{tot}$  | 250         | mW                 |
| Operating ambient temperature range                                                                    |                                                | $T_{amb}$  | -40 to +100 | $^{\circ}\text{C}$ |
| Storage temperature range                                                                              |                                                | $T_{stg}$  | -40 to +125 | $^{\circ}\text{C}$ |
| Soldering temperature <sup>(1)</sup>                                                                   |                                                | $T_{sld}$  | 260         | $^{\circ}\text{C}$ |

**Notes**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

<sup>(1)</sup> Refer to reflow profile for soldering conditions for surface mounted devices.  
Also refer to "Assembly Instructions" ([www.vishay.com/doc?80054](http://www.vishay.com/doc?80054)).

| <b>ELECTRICAL CHARACTERISTICS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified) |                                                                             |             |      |      |      |      |
|----------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------|-------------|------|------|------|------|
| PARAMETER                                                                                                | TEST CONDITION                                                              | SYMBOL      | MIN. | TYP. | MAX. | UNIT |
| <b>INPUT</b>                                                                                             |                                                                             |             |      |      |      |      |
| Forward voltage                                                                                          | $I_F = 50\text{ mA}$                                                        | $V_F$       | -    | 1.35 | 1.6  | V    |
| Junction capacitance                                                                                     | $V_R = 0$ , $f = 1\text{ MHz}$                                              | $C_j$       | -    | 8    | -    | pF   |
| <b>OUTPUT</b>                                                                                            |                                                                             |             |      |      |      |      |
| Collector emitter voltage                                                                                | $I_C = 100\text{ }\mu\text{A}$                                              | $V_{CEO}$   | 70   | -    | -    | V    |
| Emitter collector voltage                                                                                | $I_E = 100\text{ }\mu\text{A}$                                              | $V_{ECO}$   | 7    | -    | -    | V    |
| Collector dark current                                                                                   | $V_{CE} = 20\text{ V}$ , $I_F = 0\text{ A}$                                 | $I_{CEO}$   | -    | -    | 100  | nA   |
| <b>COUPLER</b>                                                                                           |                                                                             |             |      |      |      |      |
| Collector emitter saturation voltage                                                                     | $I_F = 10\text{ mA}$ , $I_C = 1\text{ mA}$                                  | $V_{CEsat}$ | -    | -    | 0.3  | V    |
| Cut-off frequency                                                                                        | $V_{CE} = 5\text{ V}$ , $I_F = 10\text{ mA}$ ,<br>$R_L = 100\text{ }\Omega$ | $f_c$       | -    | 100  | -    | kHz  |
| Coupling capacitance                                                                                     | $f = 1\text{ MHz}$                                                          | $C_k$       | -    | 0.3  | -    | pF   |

**Note**

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

| <b>CURRENT TRANSFER RATIO</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified) |                                             |          |        |      |      |      |      |
|------------------------------------------------------------------------------------------------------|---------------------------------------------|----------|--------|------|------|------|------|
| PARAMETER                                                                                            | TEST CONDITION                              | PART     | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| $I_C/I_F$                                                                                            | $V_{CE} = 5\text{ V}$ , $I_F = 5\text{ mA}$ | TCMT4100 | CTR    | 50   | -    | 600  | %    |
|                                                                                                      |                                             | TCMT4106 | CTR    | 100  | -    | 300  | %    |

| <b>SWITCHING CHARACTERISTICS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified) |                                                                                       |           |      |      |      |               |
|---------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------|-----------|------|------|------|---------------|
| PARAMETER                                                                                               | TEST CONDITION                                                                        | SYMBOL    | MIN. | TYP. | MAX. | UNIT          |
| Delay time                                                                                              | $V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\text{ }\Omega$ , (see figure 1) | $t_d$     | -    | 4    | -    | $\mu\text{s}$ |
| Rise time                                                                                               | $V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\text{ }\Omega$ , (see figure 1) | $t_r$     | -    | 5.5  | -    | $\mu\text{s}$ |
| Fall time                                                                                               | $V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\text{ }\Omega$ , (see figure 1) | $t_f$     | -    | 7.0  | -    | $\mu\text{s}$ |
| Storage time                                                                                            | $V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\text{ }\Omega$ , (see figure 1) | $t_s$     | -    | 1.5  | -    | $\mu\text{s}$ |
| Turn-on time                                                                                            | $V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\text{ }\Omega$ , (see figure 1) | $t_{on}$  | -    | 9.5  | -    | $\mu\text{s}$ |
| Turn-off time                                                                                           | $V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\text{ }\Omega$ , (see figure 1) | $t_{off}$ | -    | 8.5  | -    | $\mu\text{s}$ |
| Turn-on time                                                                                            | $V_S = 5\text{ V}$ , $I_F = 10\text{ mA}$ , $R_L = 1\text{ k}\Omega$ , (see figure 2) | $t_{on}$  | -    | 3    | -    | $\mu\text{s}$ |
| Turn-off time                                                                                           | $V_S = 5\text{ V}$ , $I_F = 10\text{ mA}$ , $R_L = 1\text{ k}\Omega$ , (see figure 2) | $t_{off}$ | -    | 20   | -    | $\mu\text{s}$ |

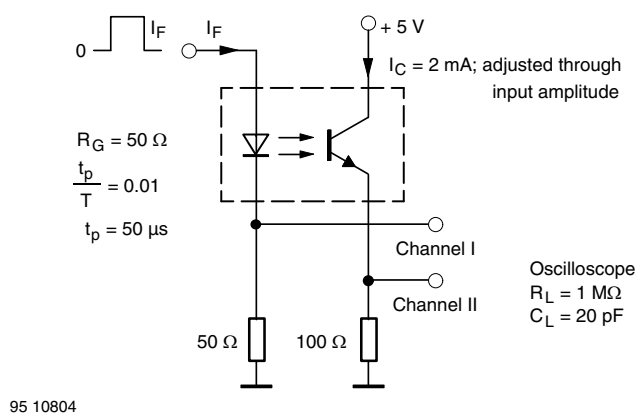


Fig. 1 - Test Circuit, Non-Saturated Operation

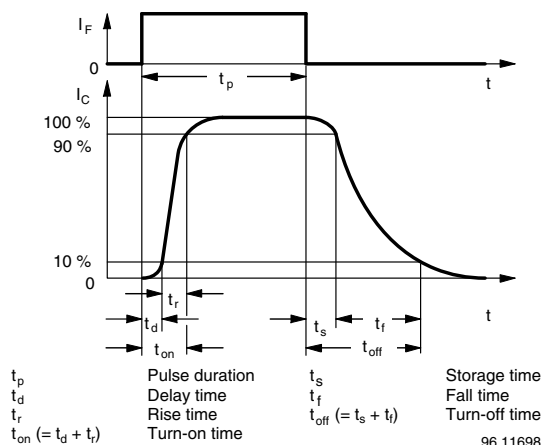


Fig. 3 - Switching Times

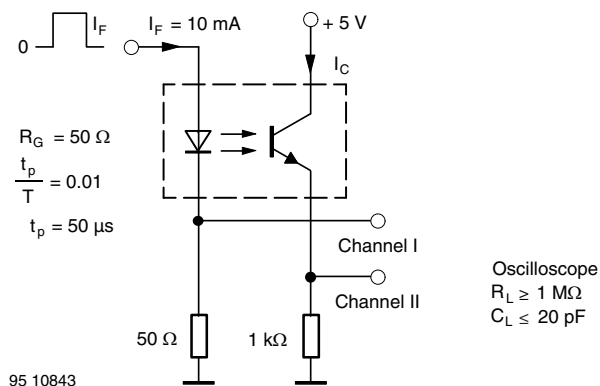


Fig. 2 - Test Circuit, Saturated Operation

| SAFETY AND INSULATION RATINGS                 |                                                                                                                                      |                   |               |                    |
|-----------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------|-------------------|---------------|--------------------|
| PARAMETER                                     | TEST CONDITION                                                                                                                       | SYMBOL            | VALUE         | UNIT               |
| Climatic classification                       | According to IEC 68 part 1                                                                                                           |                   | 40 / 110 / 21 |                    |
| Comparative tracking index                    |                                                                                                                                      | CTI               | 175           |                    |
| Maximum rated withstanding isolation voltage  | $t = 1 \text{ min}$                                                                                                                  | $V_{\text{ISO}}$  | 3750          | $V_{\text{RMS}}$   |
| Maximum transient isolation voltage           |                                                                                                                                      | $V_{\text{IOTM}}$ | 6000          | V                  |
| Maximum repetitive peak isolation voltage     |                                                                                                                                      | $V_{\text{IORM}}$ | 707           | V                  |
| Apparent charge test voltage (method A)       | $V_{\text{IORM}} \times 1.6 = V_{\text{PR}}$ , type and sample test, $t_m = 60 \text{ s}$ , partial discharge $< 5 \text{ pC}$       | $V_{\text{PR}}$   | 1132          | $V_{\text{peak}}$  |
| Apparent charge test voltage (method B)       | $V_{\text{IORM}} \times 1.875 = V_{\text{PR}}$ , 100 % production test with $t_m = 1 \text{ s}$ , partial discharge $< 5 \text{ pC}$ | $V_{\text{PR}}$   | 1326          | $V_{\text{peak}}$  |
| Isolation resistance                          | $V_{\text{IO}} = 500 \text{ V}_{\text{DC}}$ , $T_{\text{amb}} = 100 \text{ }^{\circ}\text{C}$                                        | $R_{\text{IO}}$   | $10^{11}$     | $\Omega$           |
| Isolation resistance (under fault conditions) | $V_{\text{IO}} = 500 \text{ V}_{\text{DC}}$ , $T_{\text{amb}} = T_{\text{SI}}$                                                       | $R_{\text{IO}}$   | $10^9$        | $\Omega$           |
| Output safety power                           |                                                                                                                                      | $P_{\text{SO}}$   | 265           | mW                 |
| Input safety current                          |                                                                                                                                      | $I_{\text{SI}}$   | 130           | mA                 |
| Input safety temperature                      |                                                                                                                                      | $T_{\text{SI}}$   | 150           | $^{\circ}\text{C}$ |
| Creepage distance                             |                                                                                                                                      |                   | $\geq 5$      | mm                 |
| Clearance distance                            |                                                                                                                                      |                   | $\geq 5$      | mm                 |
| Insulation thickness, reinforced rated        | Per IEC 60950 2.10.5.1                                                                                                               | DTI               | $\geq 0.4$    | mm                 |

**Note**

- As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

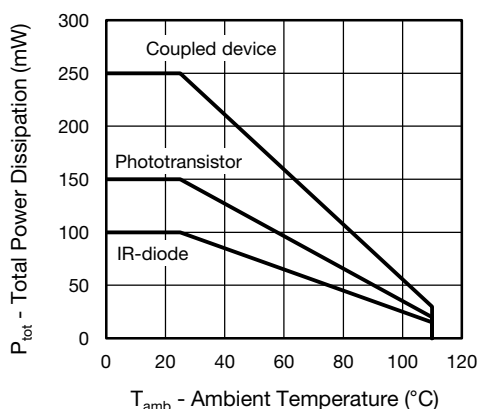
**TYPICAL CHARACTERISTICS** ( $T_{\text{amb}} = 25 \text{ }^{\circ}\text{C}$ , unless otherwise specified)


Fig. 4 - Total Power Dissipation vs. Ambient Temperature

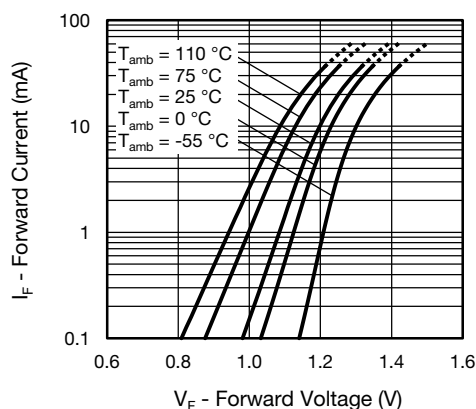


Fig. 5 - Forward Voltage vs. Forward Current

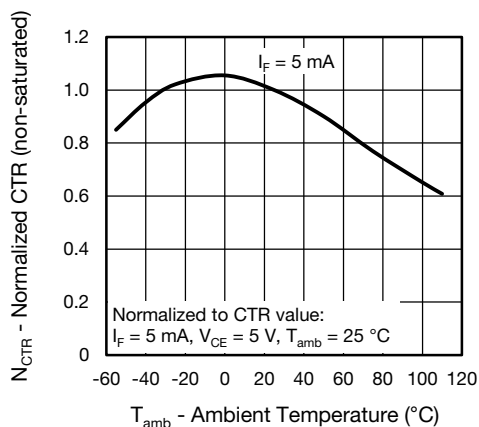


Fig. 6 - Normalized Current Transfer Ratio (non-saturated) vs. Ambient Temperature

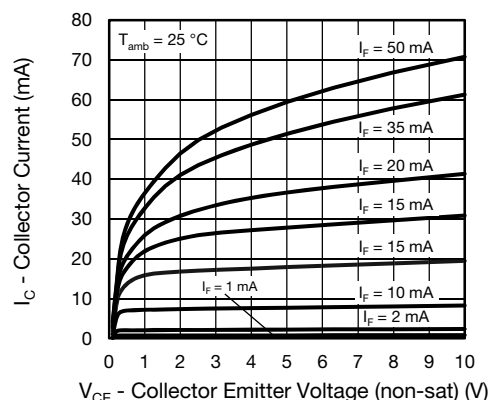


Fig. 9 - Collector Current vs. Collector Emitter Voltage (non-saturated)

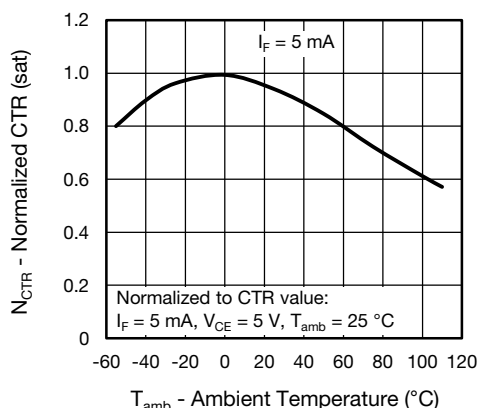


Fig. 7 - Normalized Current Transfer Ratio (saturated) vs. Ambient Temperature

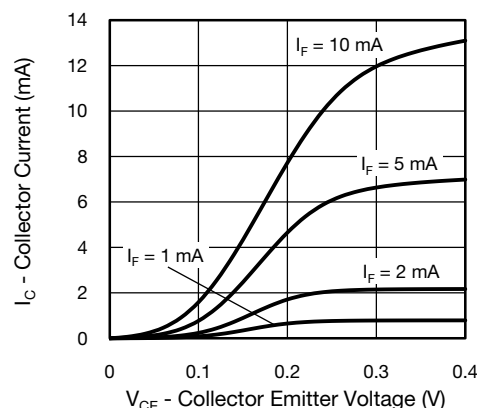


Fig. 10 - Collector Current vs. Collector Emitter Voltage (saturated)

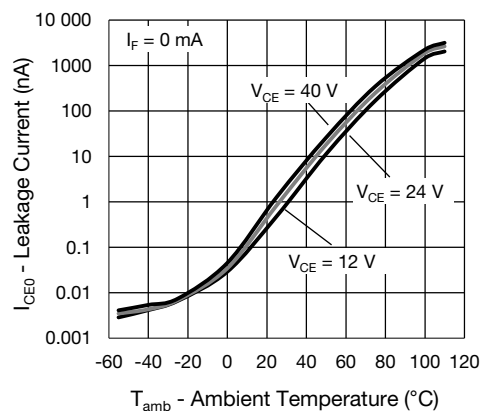


Fig. 8 - Collector Dark Current vs. Ambient Temperature

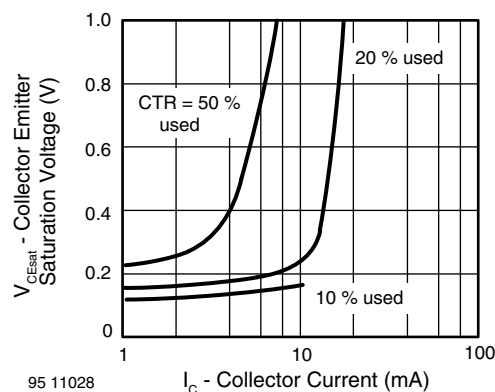


Fig. 11 - Collector Emitter Saturated Voltage vs. Collector Current

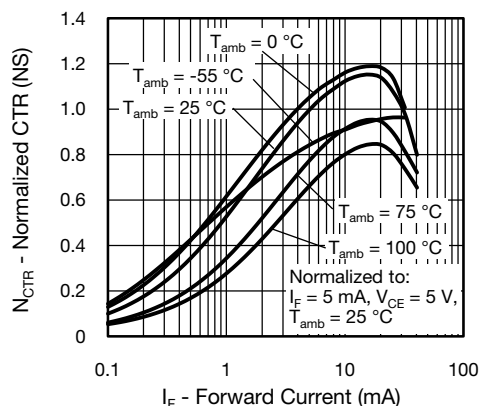


Fig. 12 - Normalized CTR (non-saturated) vs. Forward Current

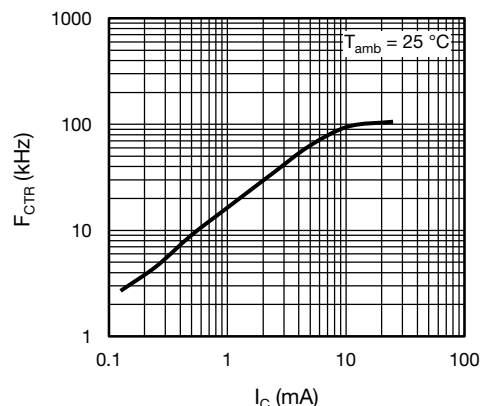
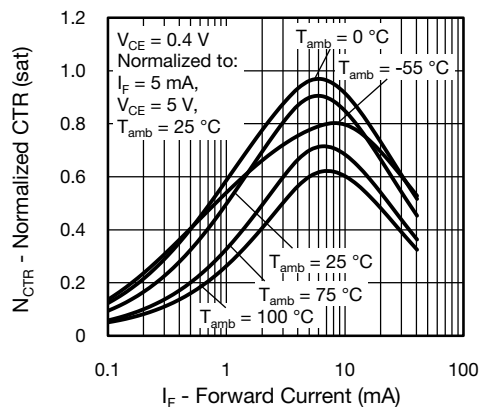

Fig. 15 -  $F_{CTR}$  vs. Collector Current


Fig. 13 - Normalized CTR (saturated) vs. Forward Current

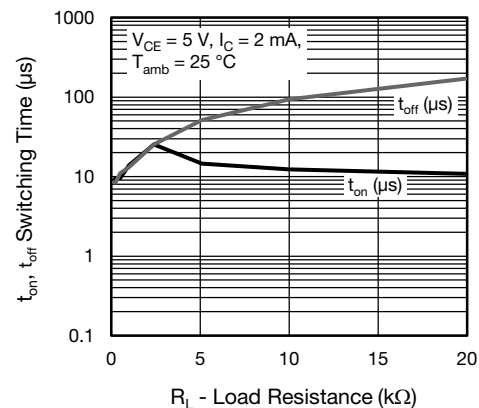


Fig. 16 - Switching Time vs. Load Resistance

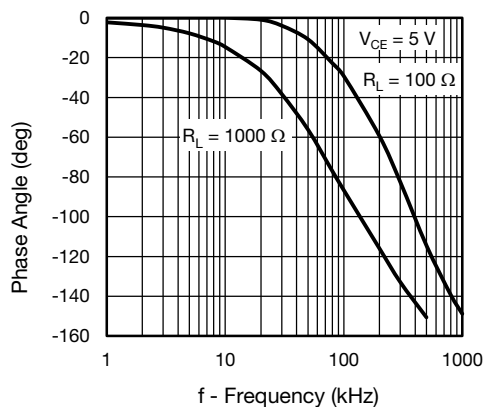


Fig. 14 - Phase Angle vs. Frequency

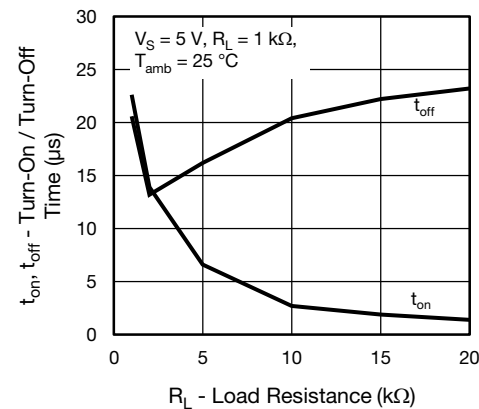


Fig. 17 - Turn-On / Turn-Off Time vs. Load Resistance

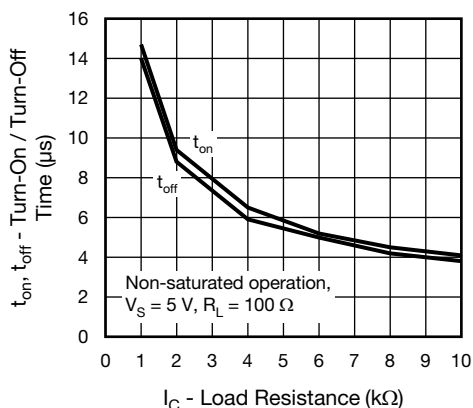
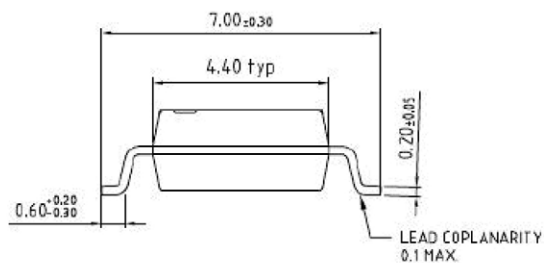
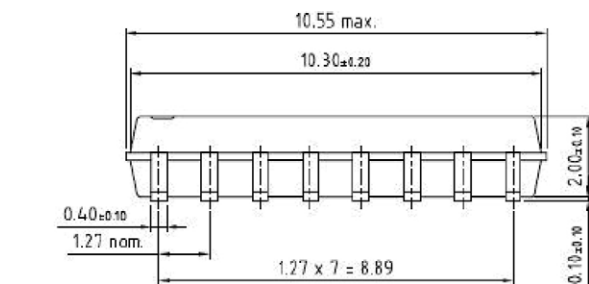
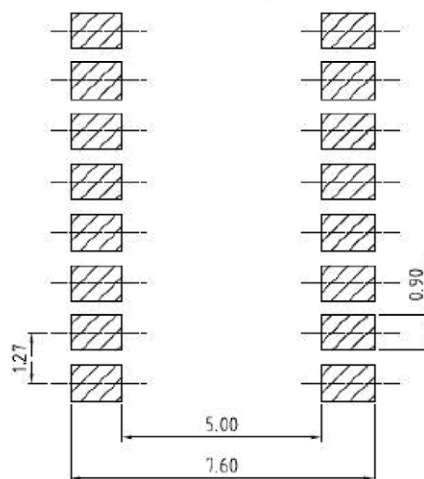


Fig. 18 - Switching Time vs. Load Resistance

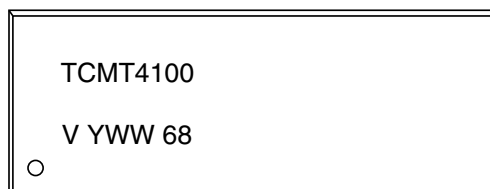
### PACKAGE DIMENSIONS (in millimeters)



### Possible footprint



### PACKAGE MARKING (example)



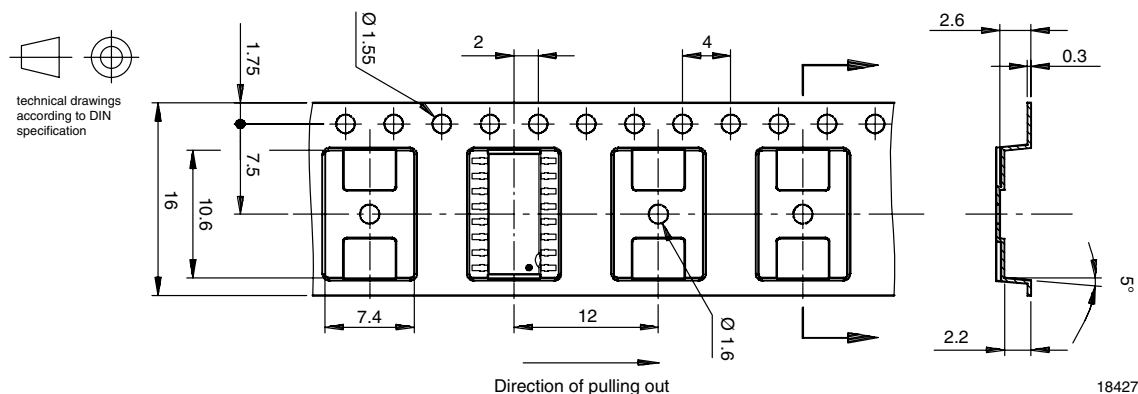
**TAPE AND REEL PACKAGING FOR TCMT410X SERIES** (in millimeters)


Fig. 19 - 2000 pcs/reel

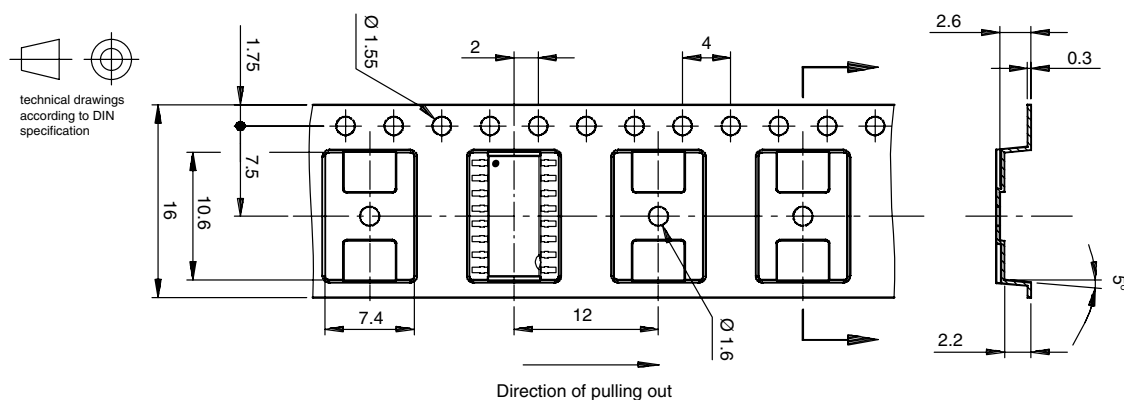
**TAPE AND REEL PACKAGING FOR TCMT410XT0 SERIES** (in millimeters)


Fig. 20 - 2000 pcs/reel

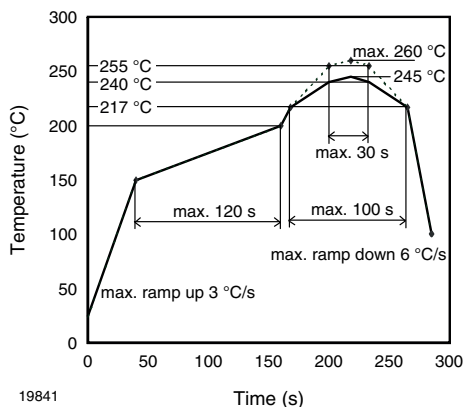
**SOLDER PROFILE**


Fig. 21 - Lead (Pb)-free Reflow Solder Profile according to J-STD-020

**HANDLING AND STORAGE CONDITIONS**

ESD level: HBM class 2

Floor life: unlimited

Conditions:  $T_{amb} < 30\text{ °C}$ , RH < 85 %

Moisture sensitivity level 1, according to J-STD-020



## Disclaimer

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